
	<h2 style="color: red;">FQP13N06</h2>
	<p>Hersteller-Teilenummer: FQP13N06</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 13A TO-220</p> <p>Datenblätter: 1.FQP13N06.pdf 2.FQP13N06.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32375 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N06
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 13A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32375 pcs Stock
detaillierte Beschreibung	N-Channel 60V 13A (Tc) 45W (Tc) Through Hole TO-
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	13A (Tc)
Rds On (Max) @ Id, Vgs	135 mOhm @ 6.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	310pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP13N06 ist neu im Original, Suche FQP13N06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N06 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP13N06: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N06L Fairchild/ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>	 <p>FQP12N65C VB FQP12N65C VB</p>	 <p>FQP13N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>
 <p>FQP13N06L FQP13N06 Original FQP13N06L FQP13N06 Original</p>	 <p>FQP12P20 AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 11.5A TO-220</p>	 <p>FQP13N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 13A TO-220</p>	 <p>FQP12P20 Fairchild/ON Semiconductor MOSFET P-CH 200V 11.5A TO-220</p>

heiße Teile

Mehr

⊗ FQP10N60C	↔ FQP10N60CF	⇒ FQP10N60C_07	D FQP10N65	↗ FQP10N65C
⊣ FQP10N80	⊗ FQP11N40C	D FQP11N40C	⇒ FQP11N50CF	↗ FQP11N50CF
⊗ FQP11N60	⊣ FQP11N60C	⊗ FQP11N65C	↔ FQP11P06	↗ FQP11P06
D FQP12N20	⊗ FQP12N60	⊣ FQP12N60	⊗ FQP12N60C	↗ FQP12N60C
⇒ FQP12N65C	↔ FQP12P10	⊗ FQP12P10	⊣ FQP12P20	↗ FQP12P20
↔ FQP13N06	⇒ FQP13N06L	D FQP13N06L	⊗ FQP13N10	⊣ FQP13N10
⊗ FQP13N10L	D FQP13N10L	⇒ FQP13N50	↔ FQP13N50	↗ FQP13N50C
⊣ FQP13N50C	⊗ FQP13N60C	↔ FQP140N03	⇒ FQP140N03L	↗ FQP14N15
⊗ FQP14N15	⊣ FQP14N30	⊗ FQP14N30	D FQP14N80	↗ FQP14N80C
↔ FQP15N16	⊗ FQP15N30	⊣ FQP15N50	⊗ FQP15N60	↗ FQP15N65

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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